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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	S08
Core Size	8-Bit
Speed	20MHz
Connectivity	I <sup>2</sup> C, LINbus, SPI, UART/USART
Peripherals	LVD, POR, PWM, WDT
Number of I/O	14
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	256 x 8
RAM Size	2K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 12x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	16-TSSOP (0.173", 4.40mm Width)
Supplier Device Package	16-TSSOP
Purchase URL	<a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/mc9s08pt16avtg">https://www.e-xfl.com/product-detail/nxp-semiconductors/mc9s08pt16avtg</a>

- Input/Output
  - Up to 37 GPIOs including one output-only pin
  - One 8-bit keyboard interrupt module (KBI)
  - Two true open-drain output pins
  - Four, ultra-high current sink pins supporting 20 mA source/sink current
- Package options
  - 44-pin LQFP
  - 32-pin LQFP
  - 20-pin SOIC; 20-pin TSSOP
  - 16-pin TSSOP

# 1 Ordering parts

## 1.1 Determining valid orderable parts

Valid orderable part numbers are provided on the web. To determine the orderable part numbers for this device, go to [freescale.com](http://freescale.com) and perform a part number search for the following device numbers: PT16 and PT8.

# 2 Part identification

## 2.1 Description

Part numbers for the chip have fields that identify the specific part. You can use the values of these fields to determine the specific part you have received.

## 2.2 Format

Part numbers for this device have the following format:

MC 9 S08 PT AA (V) B CC

## 2.3 Fields

This table lists the possible values for each field in the part number (not all combinations are valid):

Field	Description	Values
MC	Qualification status	<ul style="list-style-type: none"> <li>MC = fully qualified, general market flow</li> </ul>
9	Memory	<ul style="list-style-type: none"> <li>9 = flash based</li> </ul>
S08	Core	<ul style="list-style-type: none"> <li>S08 = 8-bit CPU</li> </ul>
PT	Device family	<ul style="list-style-type: none"> <li>PT</li> </ul>
AA	Approximate flash size in KB	<ul style="list-style-type: none"> <li>16 = 16 KB</li> <li>8 = 8 KB</li> </ul>
(V)	Mask set version	<ul style="list-style-type: none"> <li>(blank) = Any version</li> <li>A = Rev. 2 or later version, this is recommended for new design</li> </ul>

*Table continues on the next page...*

Field	Description	Values
B	Operating temperature range (°C)	<ul style="list-style-type: none"> <li>• V = -40 to 105</li> </ul>
CC	Package designator	<ul style="list-style-type: none"> <li>• LD = 44-LQFP</li> <li>• LC = 32-LQFP</li> <li>• TJ = 20-TSSOP</li> <li>• WJ = 20-SOIC</li> <li>• TG = 16-TSSOP</li> </ul>

## 2.4 Example

This is an example part number:

MC9S08PT16VLD

## 3 Parameter Classification

The electrical parameters shown in this supplement are guaranteed by various methods. To give the customer a better understanding, the following classification is used and the parameters are tagged accordingly in the tables where appropriate:

**Table 1. Parameter Classifications**

P	Those parameters are guaranteed during production testing on each individual device.
C	Those parameters are achieved by the design characterization by measuring a statistically relevant sample size across process variations.
T	Those parameters are achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted. All values shown in the typical column are within this category.
D	Those parameters are derived mainly from simulations.

### NOTE

The classification is shown in the column labeled “C” in the parameter tables where appropriate.

6. Power supply must maintain regulation within operating  $V_{DD}$  range during instantaneous and operating maximum current conditions. If the positive injection current ( $V_{in} > V_{DD}$ ) is higher than  $I_{DD}$ , the injection current may flow out of  $V_{DD}$  and could result in external power supply going out of regulation. Ensure that external  $V_{DD}$  load will shunt current higher than maximum injection current when the MCU is not consuming power, such as no system clock is present, or clock rate is very low (which would reduce overall power consumption).

**Table 3. LVD and POR Specification**

Symbol	C	Description	Min	Typ	Max	Unit	
$V_{POR}$	D	POR re-arm voltage <sup>1, 2</sup>	1.5	1.75	2.0	V	
$V_{LVDH}$	C	Falling low-voltage detect threshold - high range (LVDV = 1) <sup>3</sup>	4.2	4.3	4.4	V	
$V_{LVW1H}$	C	Falling low-voltage warning threshold - high range	Level 1 falling (LVWV = 00)	4.3	4.4	4.5	V
$V_{LVW2H}$	C		Level 2 falling (LVWV = 01)	4.5	4.5	4.6	V
$V_{LVW3H}$	C		Level 3 falling (LVWV = 10)	4.6	4.6	4.7	V
$V_{LVW4H}$	C		Level 4 falling (LVWV = 11)	4.7	4.7	4.8	V
$V_{HYSH}$	C	High range low-voltage detect/warning hysteresis	—	100	—	mV	
$V_{LVDL}$	C	Falling low-voltage detect threshold - low range (LVDV = 0)	2.56	2.61	2.66	V	
$V_{LVDW1L}$	C	Falling low-voltage warning threshold - low range	Level 1 falling (LVWV = 00)	2.62	2.7	2.78	V
$V_{LVDW2L}$	C		Level 2 falling (LVWV = 01)	2.72	2.8	2.88	V
$V_{LVDW3L}$	C		Level 3 falling (LVWV = 10)	2.82	2.9	2.98	V
$V_{LVDW4L}$	C		Level 4 falling (LVWV = 11)	2.92	3.0	3.08	V
$V_{HYSDL}$	C	Low range low-voltage detect hysteresis	—	40	—	mV	
$V_{HYSWL}$	C	Low range low-voltage warning hysteresis	—	80	—	mV	
$V_{BG}$	P	Buffered bandgap output <sup>4</sup>	1.14	1.16	1.18	V	

1. Maximum is highest voltage that POR is guaranteed.
2. POR ramp time must be longer than 20us/V to get a stable startup.
3. Rising thresholds are falling threshold + hysteresis.
4. Voltage factory trimmed at  $V_{DD} = 5.0$  V, Temp = 25 °C

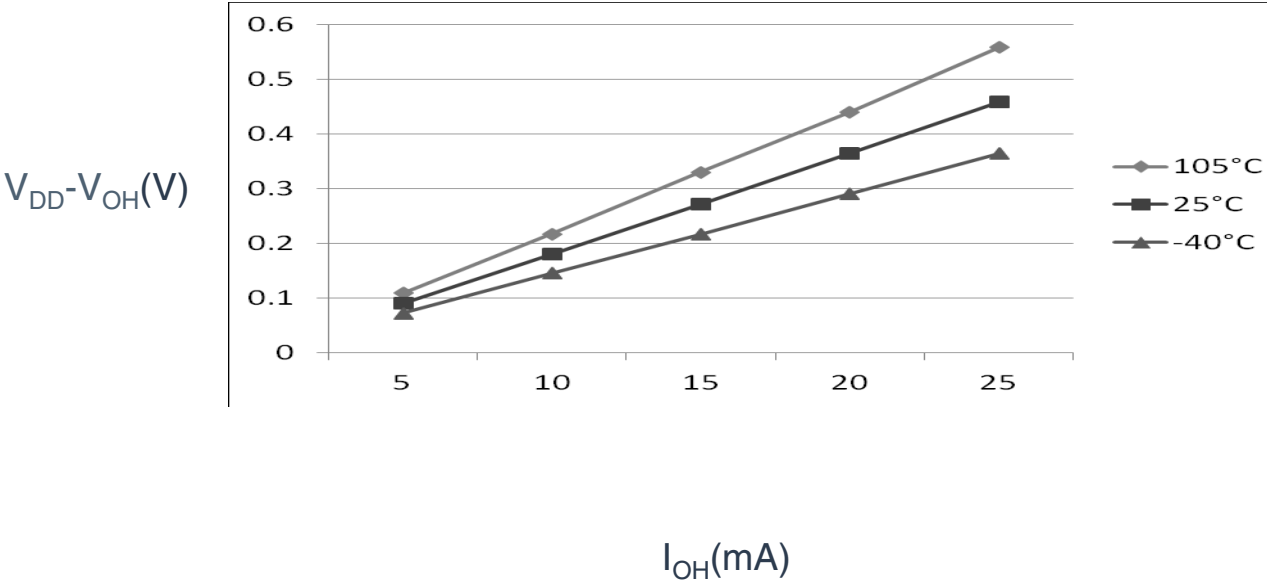


Figure 3. Typical  $I_{OH}$  Vs.  $V_{DD}-V_{OH}$  (high drive strength) ( $V_{DD} = 5\text{ V}$ )

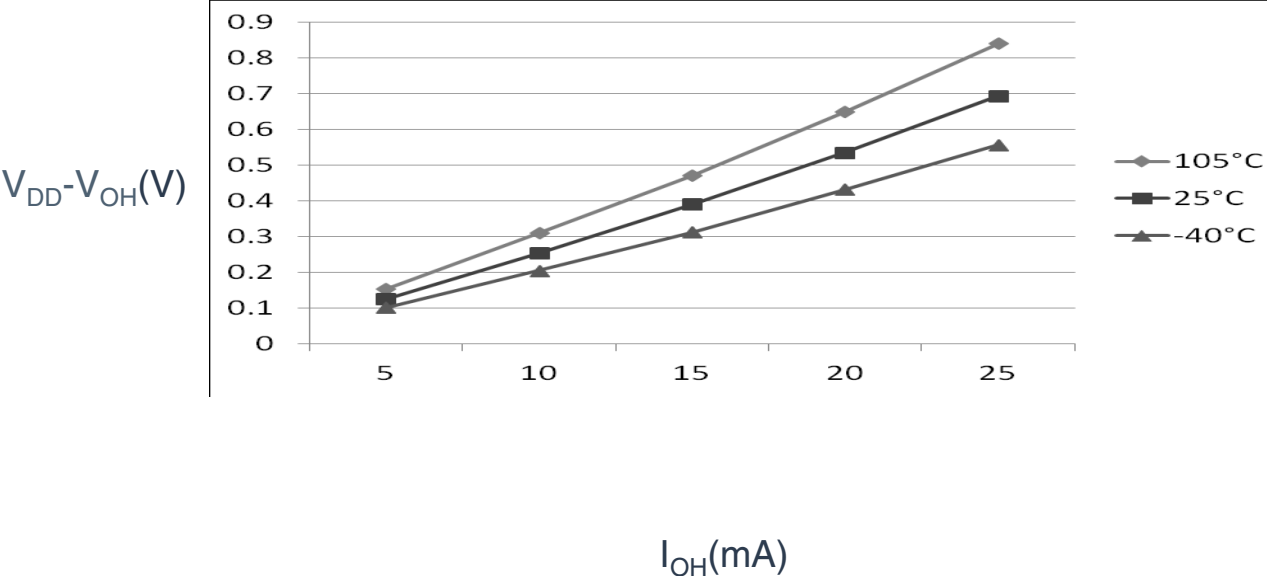


Figure 4. Typical  $I_{OH}$  Vs.  $V_{DD}-V_{OH}$  (high drive strength) ( $V_{DD} = 3\text{ V}$ )

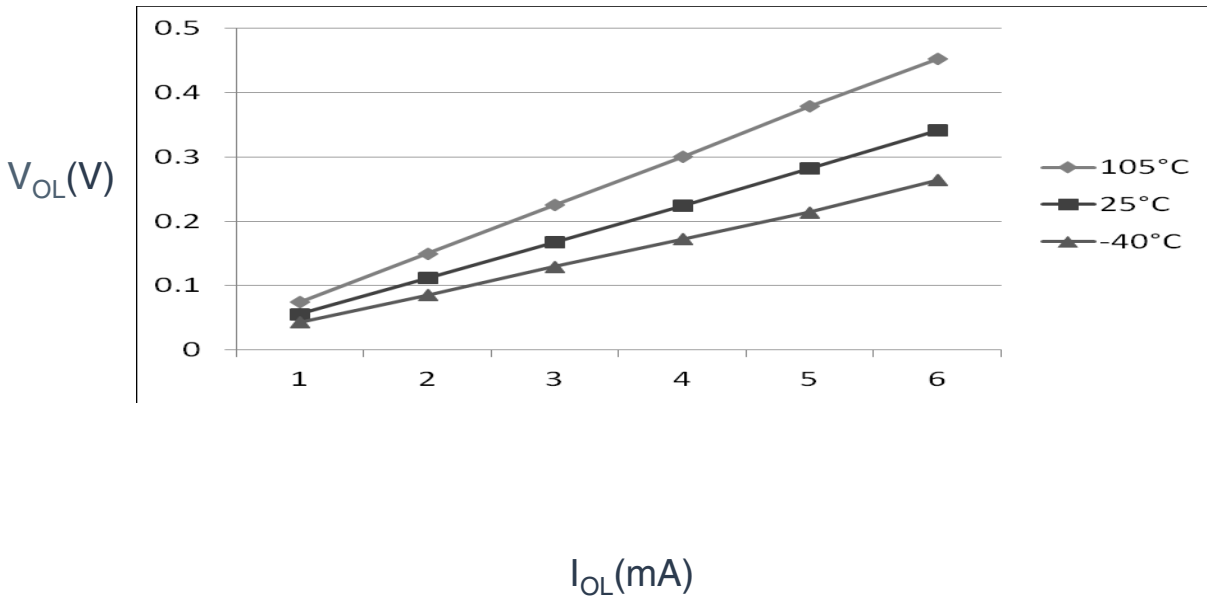


Figure 5. Typical I<sub>OL</sub> Vs. V<sub>OL</sub> (standard drive strength) (V<sub>DD</sub> = 5 V)

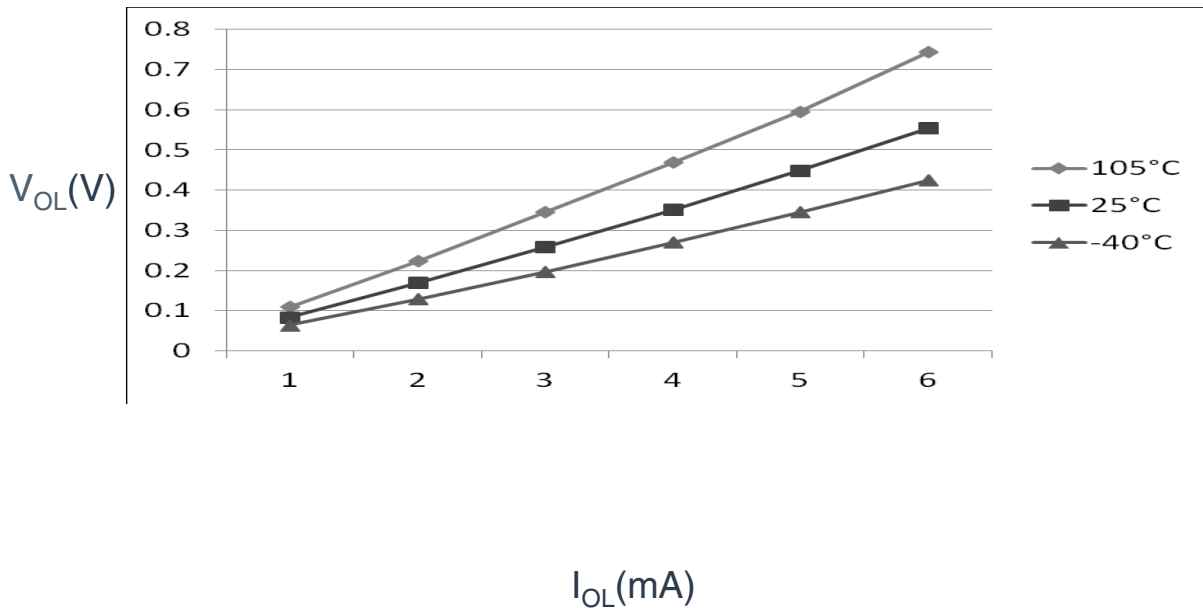


Figure 6. Typical I<sub>OL</sub> Vs. V<sub>OL</sub> (standard drive strength) (V<sub>DD</sub> = 3 V)

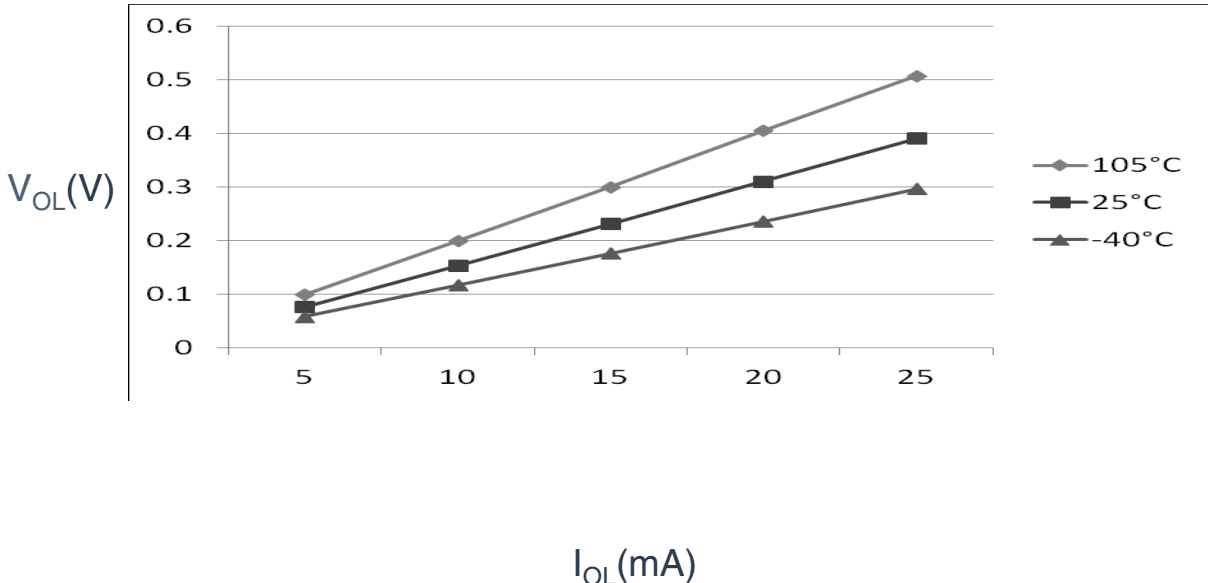


Figure 7. Typical  $I_{OL}$  Vs.  $V_{OL}$  (high drive strength) ( $V_{DD} = 5V$ )

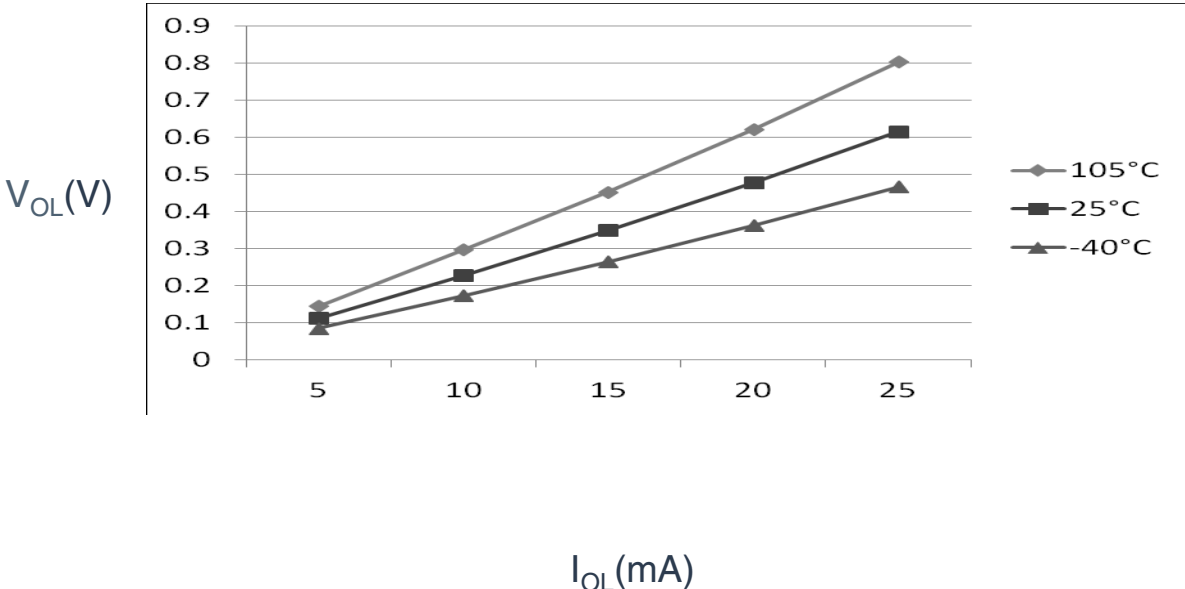


Figure 8. Typical  $I_{OL}$  Vs.  $V_{OL}$  (high drive strength) ( $V_{DD} = 3V$ )



## 5.1.2 Supply current characteristics

This section includes information about power supply current in various operating modes.

**Table 4. Supply current characteristics**

Num	C	Parameter	Symbol	Bus Freq	V <sub>DD</sub> (V)	Typical <sup>1</sup>	Max	Unit	Temp
1	C	Run supply current FEI mode, all modules on; run from flash	RI <sub>DD</sub>	20 MHz	5	7.60	—	mA	-40 to 105 °C
	C			10 MHz		4.65	—		
	C			1 MHz		1.90	—		
	C			20 MHz	3	7.05	—		
	C			10 MHz		4.40	—		
	C			1 MHz		1.85	—		
2	C	Run supply current FEI mode, all modules off & gated; run from flash	RI <sub>DD</sub>	20 MHz	5	5.88	—	mA	-40 to 105 °C
	C			10 MHz		3.70	—		
	C			1 MHz		1.85	—		
	C			20 MHz	3	5.35	—		
	C			10 MHz		3.42	—		
	C			1 MHz		1.80	—		
3	P	Run supply current FBE mode, all modules on; run from RAM	RI <sub>DD</sub>	20 MHz	5	10.9	14.0	mA	-40 to 105 °C
	C			10 MHz		6.10	—		
	C			1 MHz		1.69	—		
	C			20 MHz	3	8.18	—		
	C			10 MHz		5.14	—		
	C			1 MHz		1.44	—		
4	P	Run supply current FBE mode, all modules off & gated; run from RAM	RI <sub>DD</sub>	20 MHz	5	8.50	13.0	mA	-40 to 105 °C
	C			10 MHz		5.07	—		
	C			1 MHz		1.59	—		
	C			20 MHz	3	6.11	—		
	C			10 MHz		4.10	—		
	C			1 MHz		1.34	—		
5	C	Wait mode current FEI mode, all modules on	WI <sub>DD</sub>	20 MHz	5	5.95	—	mA	-40 to 105 °C
	C			10 MHz		3.50	—		
	C			1 MHz		1.24	—		
	C			20 MHz	3	5.45	—		
	C			10 MHz		3.25	—		
	C			1 MHz		1.20	—		
6	C	Stop3 mode supply current no clocks active (except 1kHz LPO clock) <sup>2,3</sup>	S3I <sub>DD</sub>	—	5	4.6	—	μA	-40 to 105 °C
	C			—	3	4.5	—		-40 to 105 °C
7	C	ADC adder to stop3	—	—	5	40	—	μA	-40 to 105 °C

Table continues on the next page...

**Table 4. Supply current characteristics (continued)**

Num	C	Parameter	Symbol	Bus Freq	V <sub>DD</sub> (V)	Typical <sup>1</sup>	Max	Unit	Temp
	C	ADLPC = 1 ADLSMP = 1 ADCO = 1 MODE = 10B ADICLK = 11B			3	39	—		
8	C	TSI adder to stop3 <sup>4</sup>	—	—	5	121	—	μA	-40 to 105 °C
	C	PS = 010B NSCN = 0x0F EXTCHRG = 0 REFCHRG = 0 DVOLT = 01B			3	120	—		
9	C	LVD adder to stop3 <sup>5</sup>	—	—	5	128	—	μA	-40 to 105 °C
	C				3	124	—		

1. Data in Typical column was characterized at 5.0 V, 25 °C or is typical recommended value.
2. RTC adder cause <1 μA I<sub>DD</sub> increase typically, RTC clock source is 1kHz LPO clock.
3. ACMP adder cause <10 μA I<sub>DD</sub> increase typically.
4. The current varies with TSI configuration and capacity of touch electrode. Please refer to [TSI electrical specifications](#).
5. LVD is periodically woken up from stop3 by 5% duty cycle. The period is equal to or less than 2 ms.

### 5.1.3 EMC performance

Electromagnetic compatibility (EMC) performance is highly dependent on the environment in which the MCU resides. Board design and layout, circuit topology choices, location and characteristics of external components as well as MCU software operation all play a significant role in EMC performance. The system designer should consult Freescale applications notes such as [AN2321](#), [AN1050](#), [AN1263](#), [AN2764](#), and [AN1259](#) for advice and guidance specifically targeted at optimizing EMC performance.

#### 5.1.3.1 EMC radiated emissions operating behaviors

**Table 5. EMC radiated emissions operating behaviors for 44-pin LQFP package**

Symbol	Description	Frequency band (MHz)	Typ.	Unit	Notes
V <sub>RE1</sub>	Radiated emissions voltage, band 1	0.15–50	8	dBμV	1, 2
V <sub>RE2</sub>	Radiated emissions voltage, band 2	50–150	8		
V <sub>RE3</sub>	Radiated emissions voltage, band 3	150–500	8		
V <sub>RE4</sub>	Radiated emissions voltage, band 4	500–1000	5		
V <sub>RE_IEC</sub>	IEC level	0.15–1000	N	—	2, 3

## Switching specifications

1. Determined according to IEC Standard 61967-1, *Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 1: General Conditions and Definitions* and IEC Standard 61967-2, *Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 2: Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method*. Measurements were made while the microcontroller was running basic application code. The reported emission level is the value of the maximum measured emission, rounded up to the next whole number, from among the measured orientations in each frequency range.
2.  $V_{DD} = 5.0\text{ V}$ ,  $T_A = 25\text{ °C}$ ,  $f_{OSC} = 10\text{ MHz}$  (crystal),  $f_{SYS} = 20\text{ MHz}$ ,  $f_{BUS} = 20\text{ MHz}$
3. Specified according to Annex D of IEC Standard 61967-2, *Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method*

## 5.2 Switching specifications

### 5.2.1 Control timing

Table 6. Control timing

Num	C	Rating		Symbol	Min	Typical <sup>1</sup>	Max	Unit
1	P	Bus frequency ( $t_{cyc} = 1/f_{Bus}$ )		$f_{Bus}$	DC	—	20	MHz
2	C	Internal low power oscillator frequency		$f_{LPO}$	—	1.0	—	KHz
3	D	External reset pulse width <sup>2</sup>		$t_{extrst}$	$1.5 \times t_{cyc}$	—	—	ns
4	D	Reset low drive		$t_{rstdrv}$	$34 \times t_{cyc}$	—	—	ns
5	D	BKGD/MS setup time after issuing background debug force reset to enter user or BDM modes		$t_{MSSU}$	500	—	—	ns
6	D	BKGD/MS hold time after issuing background debug force reset to enter user or BDM modes <sup>3</sup>		$t_{MSH}$	100	—	—	ns
7	D	IRQ pulse width	Asynchronous path <sup>2</sup>	$t_{LIH}$	100	—	—	ns
	D		Synchronous path <sup>4</sup>	$t_{HIL}$	$1.5 \times t_{cyc}$	—	—	ns
8	D	Keyboard interrupt pulse width	Asynchronous path <sup>2</sup>	$t_{LIH}$	100	—	—	ns
	D		Synchronous path	$t_{HIL}$	$1.5 \times t_{cyc}$	—	—	ns
9	C	Port rise and fall time - standard drive strength (load = 50 pF) <sup>5</sup>	—	$t_{Rise}$	—	10.2	—	ns
	C		—	$t_{Fall}$	—	9.5	—	ns
	C	Port rise and fall time - high drive strength (load = 50 pF) <sup>5</sup>	—	$t_{Rise}$	—	5.4	—	ns
	C		—	$t_{Fall}$	—	4.6	—	ns

1. Typical values are based on characterization data at  $V_{DD} = 5.0\text{ V}$ ,  $25\text{ °C}$  unless otherwise stated.
2. This is the shortest pulse that is guaranteed to be recognized as a reset pin request.
3. To enter BDM mode following a POR, BKGD/MS must be held low during the powerup and for a hold time of  $t_{MSH}$  after  $V_{DD}$  rises above  $V_{LVD}$ .
4. This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In stop mode, the synchronizer is bypassed so shorter pulses can be recognized.
5. Timing is shown with respect to 20%  $V_{DD}$  and 80%  $V_{DD}$  levels. Temperature range  $-40\text{ °C}$  to  $105\text{ °C}$ .

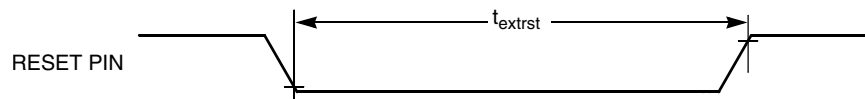


Figure 9. Reset timing

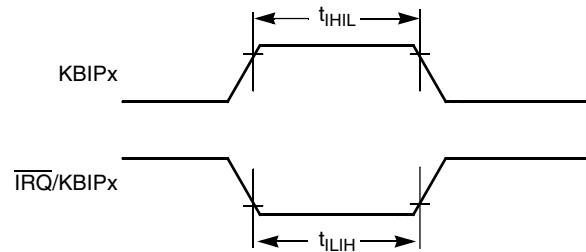


Figure 10. IRQ/KBIPx timing

### 5.2.2 Debug trace timing specifications

Table 7. Debug trace operating behaviors

Symbol	Description	Min.	Max.	Unit
$t_{cyc}$	Clock period	Frequency dependent		MHz
$t_{wl}$	Low pulse width	2	—	ns
$t_{wh}$	High pulse width	2	—	ns
$t_r$	Clock and data rise time	—	3	ns
$t_f$	Clock and data fall time	—	3	ns
$t_s$	Data setup	3	—	ns
$t_h$	Data hold	2	—	ns

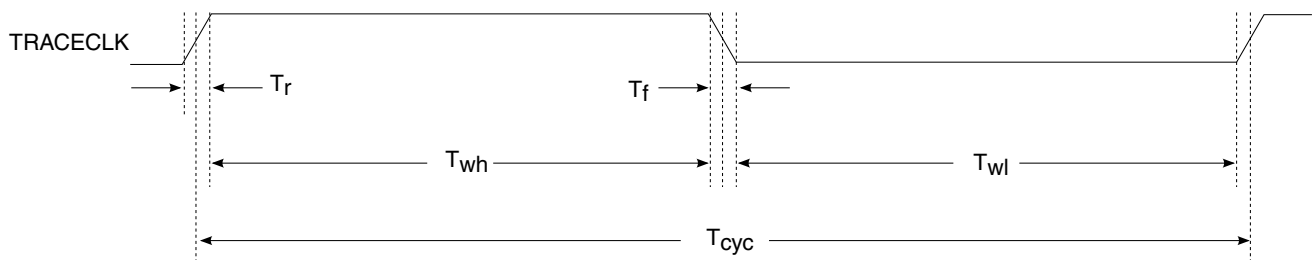


Figure 11. TRACE\_CLKOUT specifications

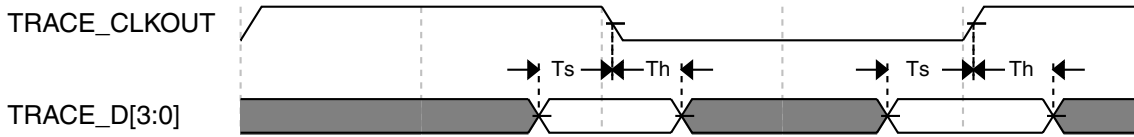


Figure 12. Trace data specifications

### 5.2.3 FTM module timing

Synchronizer circuits determine the shortest input pulses that can be recognized or the fastest clock that can be used as the optional external source to the timer counter. These synchronizers operate from the current bus rate clock.

Table 8. FTM input timing

No.	C	Function	Symbol	Min	Max	Unit
1	D	External clock frequency	$f_{TCLK}$	0	$f_{Bus}/4$	Hz
2	D	External clock period	$t_{TCLK}$	4	—	$t_{cyc}$
3	D	External clock high time	$t_{clkh}$	1.5	—	$t_{cyc}$
4	D	External clock low time	$t_{clkl}$	1.5	—	$t_{cyc}$
5	D	Input capture pulse width	$t_{iCPW}$	1.5	—	$t_{cyc}$

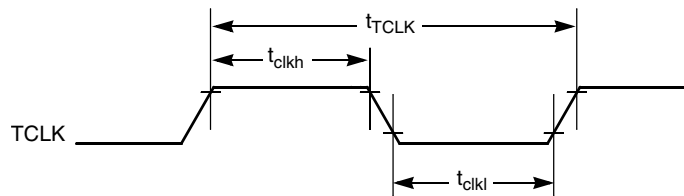


Figure 13. Timer external clock

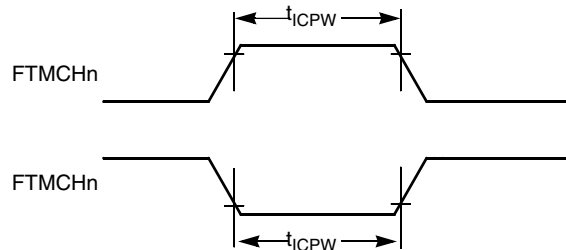


Figure 14. Timer input capture pulse

## 5.3 Thermal specifications

### 5.3.1 Thermal characteristics

This section provides information about operating temperature range, power dissipation, and package thermal resistance. Power dissipation on I/O pins is usually small compared to the power dissipation in on-chip logic and voltage regulator circuits, and it is user-determined rather than being controlled by the MCU design. To take  $P_{I/O}$  into account in power calculations, determine the difference between actual pin voltage and  $V_{SS}$  or  $V_{DD}$  and multiply by the pin current for each I/O pin. Except in cases of unusually high pin current (heavy loads), the difference between pin voltage and  $V_{SS}$  or  $V_{DD}$  will be very small.

**Table 9. Thermal characteristics**

Rating	Symbol	Value	Unit
Operating temperature range (packaged)	$T_A$ <sup>1</sup>	$T_L$ to $T_H$ -40 to 105	°C
Junction temperature range	$T_J$	-40 to 150	°C
Thermal resistance single-layer board			
44-pin LQFP	$R_{\theta JA}$	76	°C/W
32-pin LQFP	$R_{\theta JA}$	88	°C/W
20-pin SOIC	$R_{\theta JA}$	82	°C/W
20-pin TSSOP	$R_{\theta JA}$	116	°C/W
16-pin TSSOP	$R_{\theta JA}$	130	°C/W
Thermal resistance four-layer board			
44-pin LQFP	$R_{\theta JA}$	54	°C/W
32-pin LQFP	$R_{\theta JA}$	59	°C/W
20-pin SOIC	$R_{\theta JA}$	54	°C/W
20-pin TSSOP	$R_{\theta JA}$	76	°C/W
16-pin TSSOP	$R_{\theta JA}$	87	°C/W

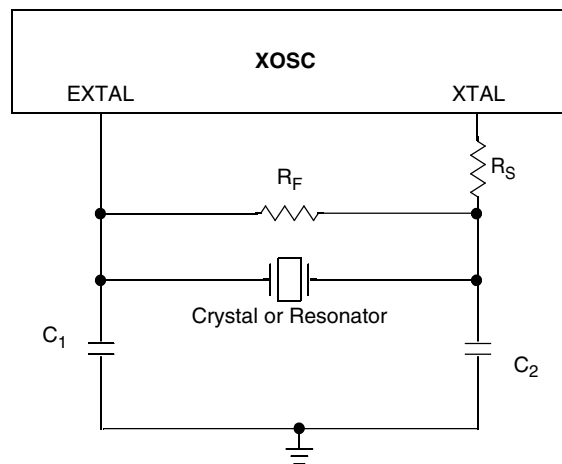
- Maximum  $T_A$  can be exceeded only if the user ensures that  $T_J$  does not exceed the maximum. The simplest method to determine  $T_J$  is:  $T_J = T_A + R_{\theta JA} \times \text{chip power dissipation}$ .

## 6 Peripheral operating requirements and behaviors

**Table 10. XOSC and ICS specifications (temperature range = -40 to 105 °C ambient)  
(continued)**

Num	C	Characteristic	Symbol	Min	Typical <sup>1</sup>	Max	Unit
13	C	Long term jitter of DCO output clock (averaged over 2 ms interval) <sup>8</sup>	$C_{\text{Jitter}}$	—	0.02	0.2	% $f_{\text{dco}}$

1. Data in Typical column was characterized at 5.0 V, 25 °C or is typical recommended value.
2. When ICS is configured for FEE or FBE mode, input clock source must be divisible using RDIV to within the range of 31.25 kHz to 39.0625 kHz.
3. See crystal or resonator manufacturer's recommendation.
4. Load capacitors ( $C_1, C_2$ ), feedback resistor ( $R_F$ ) and series resistor ( $R_S$ ) are incorporated internally when RANGE = HGO = 0.
5. This parameter is characterized and not tested on each device.
6. Proper PC board layout procedures must be followed to achieve specifications.
7. This specification applies to any time the FLL reference source or reference divider is changed, trim value changed, or changing from FLL disabled (FBELP, FBILP) to FLL enabled (FEI, FEE, FBE, FBI). If a crystal/resonator is being used as the reference, this specification assumes it is already running.
8. Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum  $f_{\text{Bus}}$ . Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the FLL circuitry via  $V_{\text{DD}}$  and  $V_{\text{SS}}$  and variation in crystal oscillator frequency increase the  $C_{\text{Jitter}}$  percentage for a given interval.


**Figure 15. Typical crystal or resonator circuit**

## 6.2 NVM specifications

This section provides details about program/erase times and program/erase endurance for the flash and EEPROM memories.

**Table 11. Flash characteristics**

C	Characteristic	Symbol	Min <sup>1</sup>	Typical <sup>2</sup>	Max <sup>3</sup>	Unit <sup>4</sup>
D	Supply voltage for program/erase -40 °C to 105 °C	$V_{\text{prog/erase}}$	2.7	—	5.5	V
D	Supply voltage for read operation	$V_{\text{Read}}$	2.7	—	5.5	V

Table continues on the next page...

**Table 11. Flash characteristics (continued)**

C	Characteristic	Symbol	Min <sup>1</sup>	Typical <sup>2</sup>	Max <sup>3</sup>	Unit <sup>4</sup>
D	NVM Bus frequency	$f_{\text{NVMBUS}}$	1	—	25	MHz
D	NVM Operating frequency	$f_{\text{NVMOP}}$	0.8	1	1.05	MHz
D	Erase Verify All Blocks	$t_{\text{VFYALL}}$	—	—	17338	$t_{\text{cyc}}$
D	Erase Verify Flash Block	$t_{\text{RD1BLK}}$	—	—	16913	$t_{\text{cyc}}$
D	Erase Verify EEPROM Block	$t_{\text{RD1BLK}}$	—	—	810	$t_{\text{cyc}}$
D	Erase Verify Flash Section	$t_{\text{RD1SEC}}$	—	—	484	$t_{\text{cyc}}$
D	Erase Verify EEPROM Section	$t_{\text{DRD1SEC}}$	—	—	555	$t_{\text{cyc}}$
D	Read Once	$t_{\text{RDONCE}}$	—	—	450	$t_{\text{cyc}}$
D	Program Flash (2 word)	$t_{\text{PGM2}}$	0.12	0.12	0.29	ms
D	Program Flash (4 word)	$t_{\text{PGM4}}$	0.20	0.21	0.46	ms
D	Program Once	$t_{\text{PGMONCE}}$	0.20	0.21	0.21	ms
D	Program EEPROM (1 Byte)	$t_{\text{DPGM1}}$	0.10	0.10	0.27	ms
D	Program EEPROM (2 Byte)	$t_{\text{DPGM2}}$	0.17	0.18	0.43	ms
D	Program EEPROM (3 Byte)	$t_{\text{DPGM3}}$	0.25	0.26	0.60	ms
D	Program EEPROM (4 Byte)	$t_{\text{DPGM4}}$	0.32	0.33	0.77	ms
D	Erase All Blocks	$t_{\text{ERSALL}}$	96.01	100.78	101.49	ms
D	Erase Flash Block	$t_{\text{ERSBLK}}$	95.98	100.75	101.44	ms
D	Erase Flash Sector	$t_{\text{ERSPG}}$	19.10	20.05	20.08	ms
D	Erase EEPROM Sector	$t_{\text{DERSPG}}$	4.81	5.05	20.57	ms
D	Unsecure Flash	$t_{\text{UNSECU}}$	96.01	100.78	101.48	ms
D	Verify Backdoor Access Key	$t_{\text{VFYKEY}}$	—	—	464	$t_{\text{cyc}}$
D	Set User Margin Level	$t_{\text{MLOADU}}$	—	—	407	$t_{\text{cyc}}$
C	FLASH Program/erase endurance $T_L$ to $T_H = -40\text{ °C}$ to $105\text{ °C}$	$n_{\text{FLPE}}$	10 k	100 k	—	Cycles
C	EEPROM Program/erase endurance $T_L$ to $T_H = -40\text{ °C}$ to $105\text{ °C}$	$n_{\text{FLPE}}$	50 k	500 k	—	Cycles
C	Data retention at an average junction temperature of $T_{\text{Javg}} = 85\text{ °C}$ after up to 10,000 program/erase cycles	$t_{\text{D\_ret}}$	15	100	—	years

1. Minimum times are based on maximum  $f_{\text{NVMOP}}$  and maximum  $f_{\text{NVMBUS}}$
2. Typical times are based on typical  $f_{\text{NVMOP}}$  and maximum  $f_{\text{NVMBUS}}$
3. Maximum times are based on typical  $f_{\text{NVMOP}}$  and typical  $f_{\text{NVMBUS}}$  plus aging
4.  $t_{\text{cyc}} = 1 / f_{\text{NVMBUS}}$

Program and erase operations do not require any special power sources other than the normal  $V_{\text{DD}}$  supply. For more detailed information about program/erase operations, see the Memory section.



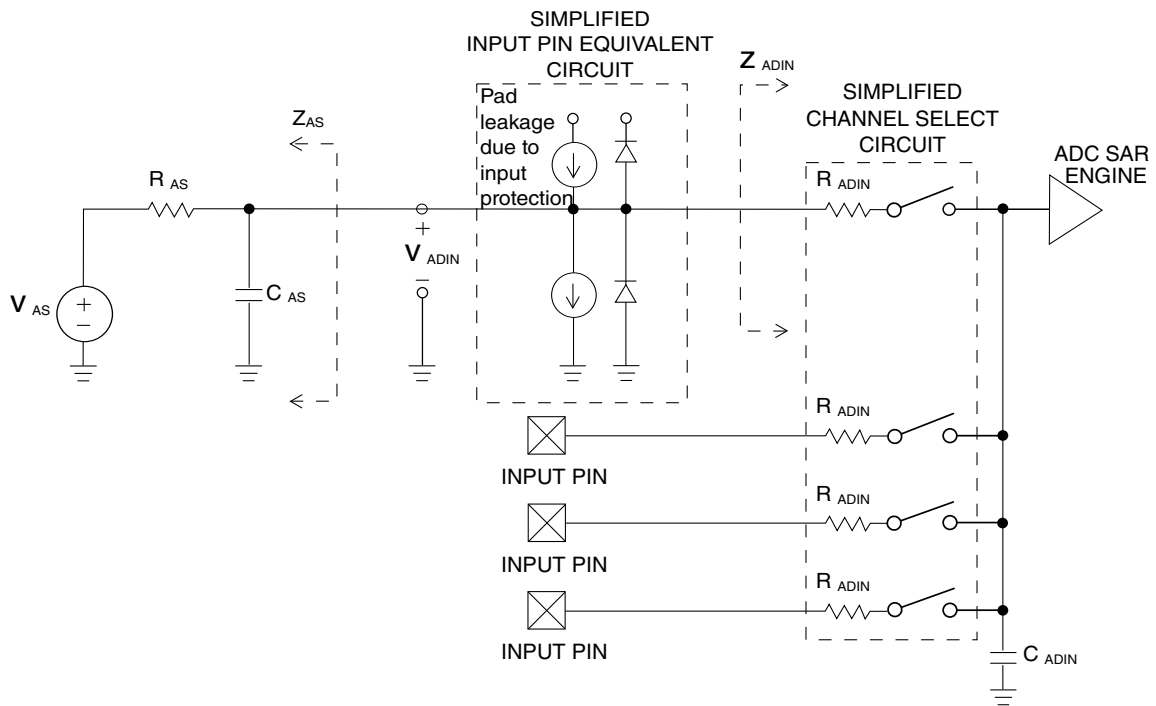


Figure 16. ADC input impedance equivalency diagram

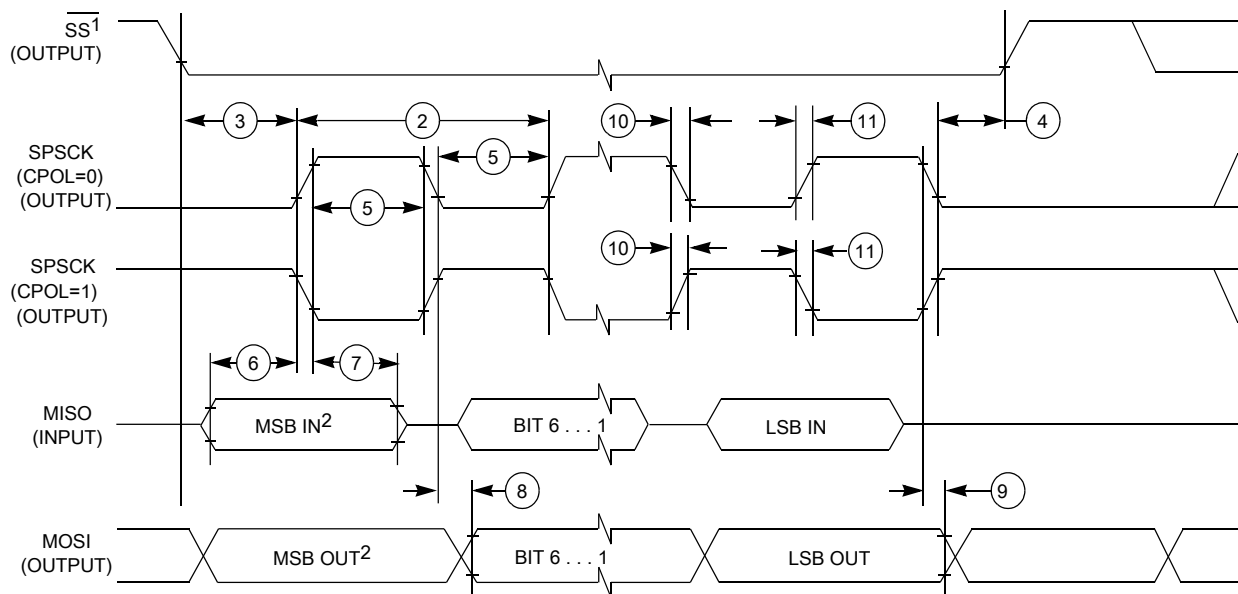
Table 13. 12-bit ADC Characteristics ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SSA}$ )

Characteristic	Conditions	C	Symb	Min	Typ <sup>1</sup>	Max	Unit
Supply current		T	$I_{DDA}$	—	133	—	$\mu A$
ADLPC = 1							
ADLSMP = 1							
ADCO = 1							
Supply current		T	$I_{DDA}$	—	218	—	$\mu A$
ADLPC = 1							
ADLSMP = 0							
ADCO = 1							
Supply current		T	$I_{DDA}$	—	327	—	$\mu A$
ADLPC = 0							
ADLSMP = 1							
ADCO = 1							
Supply current		T	$I_{DDAD}$	—	582	990	$\mu A$
ADLPC = 0							
ADLSMP = 0							
ADCO = 1							
Supply current	Stop, reset, module off	T	$I_{DDA}$	—	0.011	1	$\mu A$
ADC asynchronous clock source	High speed (ADLPC = 0)	P	$f_{ADACK}$	2	3.3	5	MHz

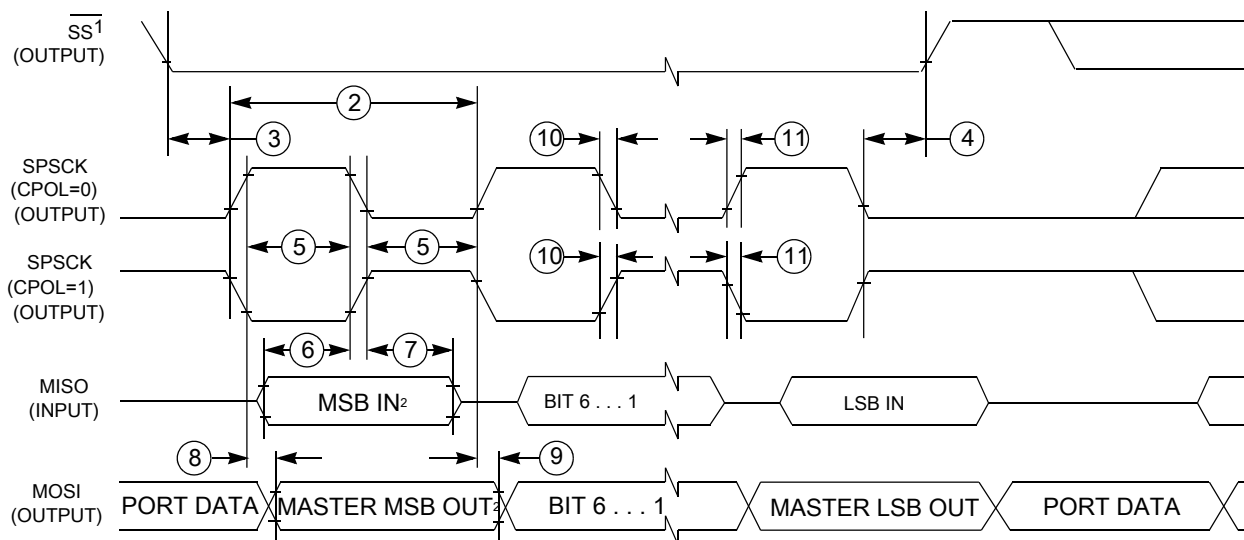
Table continues on the next page...

**Table 15. SPI master mode timing (continued)**

Nu m.	Symbol	Description	Min.	Max.	Unit	Comment
	$t_{FI}$	Fall time input				
11	$t_{RO}$	Rise time output	—	25	ns	—
	$t_{FO}$	Fall time output				



1. If configured as an output.
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

**Figure 17. SPI master mode timing (CPHA=0)**


1. If configured as output
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

**Figure 18. SPI master mode timing (CPHA=1)**

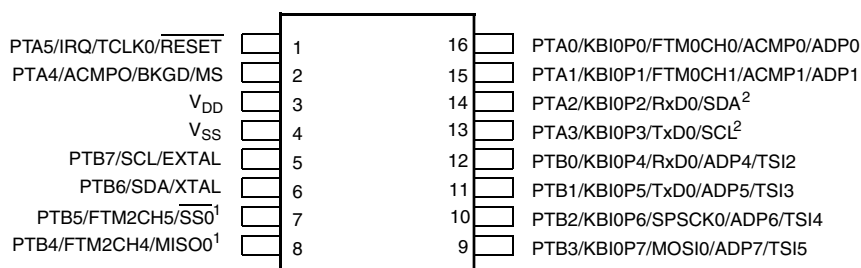
**Table 18. Pin availability by package pin-count (continued)**

Pin Number				Lowest Priority <-- --> Highest				
44-LQFP	32-LQFP	20-TSSOP	16-TSSOP	Port Pin	Alt 1	Alt 2	Alt 3	Alt 4
18	—	—	—	PTD5	—	—	—	—
19	13	11	—	PTC1	—	FTM2CH1	ADP9	TSI7
20	14	12	—	PTC0	—	FTM2CH0	ADP8	TSI6
21	15	13	9	PTB3	KBI0P7	MOSI0	ADP7	TSI5
22	16	14	10	PTB2	KBI0P6	SPSCK0	ADP6	TSI4
23	17	15	11	PTB1	KBI0P5	TXD0	ADP5	TSI3
24	18	16	12	PTB0	KBI0P4	RXD0	ADP4	TSI2
25	19	—	—	PTA7	—	FTM2FAULT2	ADP3	TSI1
26	20	—	—	PTA6	—	FTM2FAULT1	ADP2	TSI0
27	—	—	—	—	—	—	—	V <sub>SS</sub>
28	—	—	—	—	—	—	—	V <sub>DD</sub>
29	—	—	—	PTD4	—	—	—	—
30	21	—	—	PTD3	—	—	—	TSI15
31	22	—	—	PTD2	—	—	—	TSI14
32	23	17	13	PTA3 <sup>2</sup>	KBI0P3	TXD0	SCL	—
33	24	18	14	PTA2 <sup>2</sup>	KBI0P2	RXD0	SDA	—
34	25	19	15	PTA1	KBI0P1	FTM0CH1	ACMP1	ADP1
35	26	20	16	PTA0	KBI0P0	FTM0CH0	ACMP0	ADP0
36	27	—	—	PTC7	—	TxD1	—	TSI13
37	28	—	—	PTC6	—	RxD1	—	TSI12
38	—	—	—	PTE2	—	MISO0	—	—
39	—	—	—	PTE1	—	MOSI0	—	—
40	—	—	—	PTE0	—	SPSCK0	—	—
41	29	—	—	PTC5	—	FTM0CH1	—	TSI11
42	30	—	—	PTC4	—	FTM0CH0	—	TSI10
43	31	1	1	PTA5	IRQ	TCLK0	—	RESET
44	32	2	2	PTA4	—	ACMPO	BKGD	MS

1. This is a high current drive pin when operated as output.
2. This is a true open-drain pin when operated as output.

### Note

When an alternative function is first enabled, it is possible to get a spurious edge to the module. User software must clear any associated flags before interrupts are enabled. The table above illustrates the priority if multiple modules are enabled. The highest priority module will have control over the pin. Selecting a higher priority pin function with a lower priority function



Pins in **bold** are not available on less pin-count packages.

1. High source/sink current pins
2. True open drain pins

**Figure 24. MC9S08PT16 16-pin TSSOP package**

## 9 Revision history

The following table provides a revision history for this document.

**Table 19. Revision history**

Rev. No.	Date	Substantial Changes
1	7/2012	Initial public release
2	09/2014	<ul style="list-style-type: none"> <li>• Updated <math>V_{OH}</math> and <math>V_{OL}</math> in <a href="#">DC characteristics</a></li> <li>• Added footnote on the <math>S3I_{DD}</math> in <a href="#">Supply current characteristics</a></li> <li>• Added <a href="#">EMC radiated emissions operating behaviors</a></li> <li>• Updated the typical of <math>f_{int\_t}</math> to 31.25 kHz and updated footnote to <math>t_{Acquire}</math> in <a href="#">External oscillator (XOSC) and ICS characteristics</a></li> <li>• Updated the assumption for all the timing values in <a href="#">SPI switching specifications</a></li> <li>• Updated the rating descriptions for <math>t_{Rise}</math> and <math>t_{Fall}</math> in <a href="#">Control timing</a></li> <li>• Updated the part number format to add new field for new part numbers in <a href="#">Fields</a></li> </ul>
3	06/2015	<ul style="list-style-type: none"> <li>• Corrected the Min. of the <math>t_{extrst}</math> in <a href="#">Control timing</a></li> <li>• Updated <a href="#">Thermal characteristics</a> to add footnote to the <math>T_A</math> and removed redundant information. Updated the symbol of <math>\theta_{JA}</math> to <math>R_{\theta JA}</math>.</li> </ul>



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